

20 V, single N-channel Trench MOSFET Rev. 3 — 23 March 2012

Product data sheet

1. **Product profile**

1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Very fast switching
- Low threshold voltage
- Trench MOSFET technology

1.3 Applications

- Relay driver
- High-speed line driver

1.4 Quick reference data

- ESD protection up to 2 kV
- Ultra thin package profile of 0.37mm
- Low-side loadswitch
- Switching circuits

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V_{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C	<u>[1]</u>	-	-	1	А
Static cha	aracteristics						
R_{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I _D = 500 mA; T _j = 25 °C		-	290	380	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



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2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		5
2	S	source		
3	D drain	2 Transparent top view		
			DFN1006B-3 (SOT883B)	s
				017aaa255

3. Ordering information

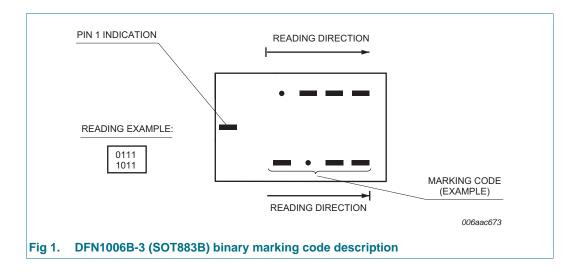
Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMZB290UNE	DFN1006B-3	Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B				

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMZB290UNE	0000 0110

[1] For DFN1006B-3 (SOT883B) binary marking code description see Figure 1.

4.1 Binary marking code description



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5. Limiting values

Table 5. Limiting values

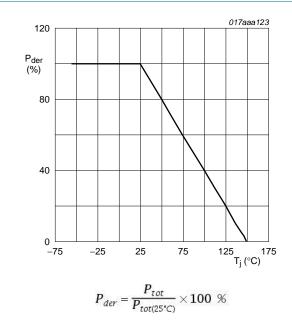
In accordance with the Absolute Maximum Rating System (IEC 60134).

	_					
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C	<u>[1]</u>	-	1	А
		$V_{GS} = 4.5 \text{ V}; \text{ T}_{amb} = 100 ^{\circ}\text{C}$	<u>[1]</u>	-	625	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	4	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	360	mW
			[1]	-	715	mW
		T _{sp} = 25 °C		-	2700	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode					
I _S	source current	T _{amb} = 25 °C	<u>[1]</u>	-	680	mA
ESD maximu	m rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V

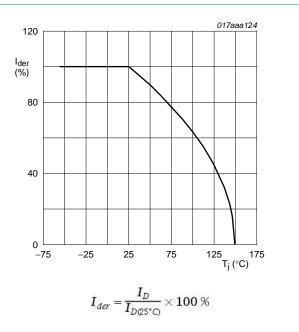
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



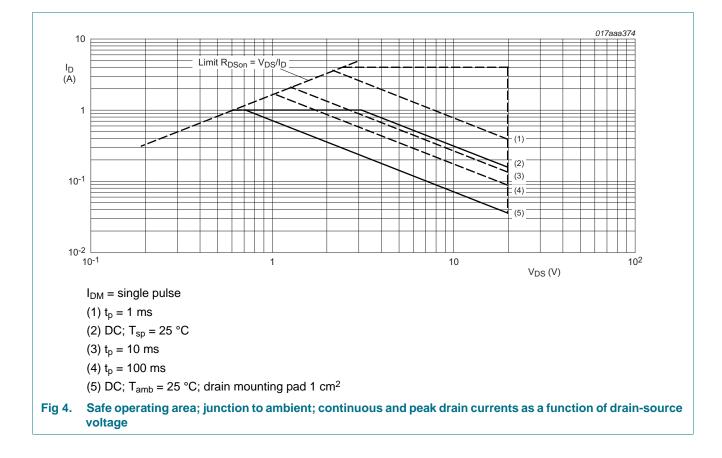






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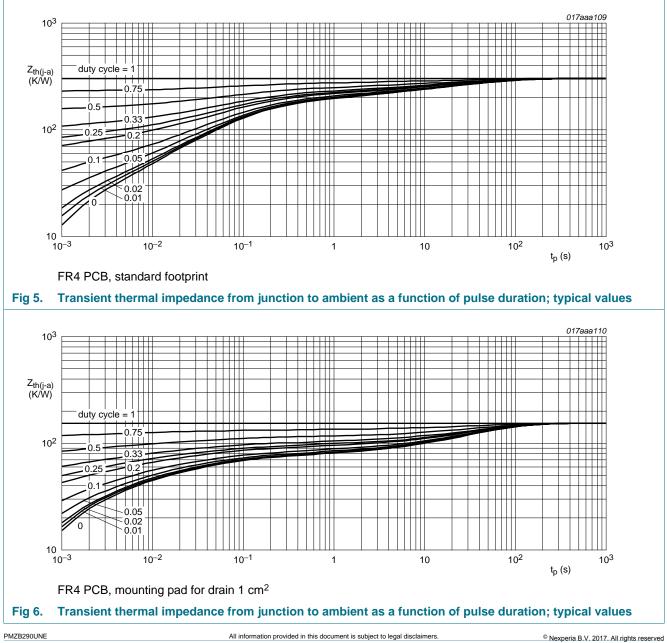


6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	<u>[1]</u>	-	305	360	K/W
	from junction to ambient		[2]	-	150	175	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	40	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

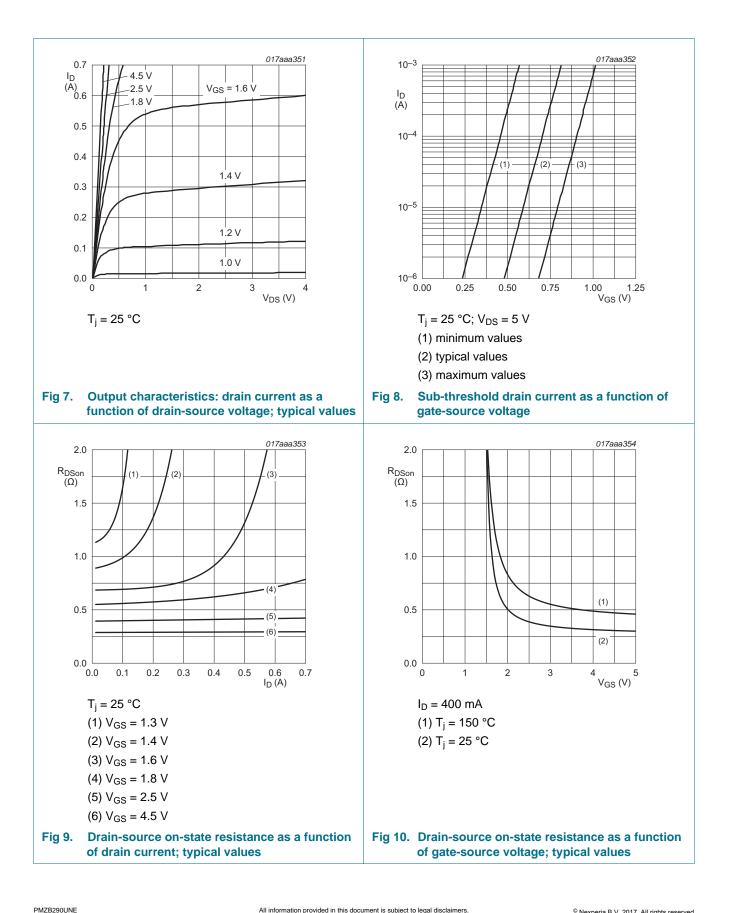


7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
-	aracteristics			.76		•••••
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	20	-	-	V
V _{GSth}	gate-source threshold voltage	$I_D = 250 \ \mu\text{A}; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^\circ\text{C}$	0.5	0.75	0.95	V
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = 8 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	2	μA
		$V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; \text{T}_{j} = 25 ^{\circ}\text{C}$	-	-	2	μA
		$V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; \text{ T}_{j} = 25 \text{ °C}$	-	-	500	nA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	500	nA
R _{DSon}	DSon drain-source on-state resistance	V_{GS} = 4.5 V; I _D = 500 mA; T _j = 25 °C	-	290	380	mΩ
		V_{GS} = 4.5 V; I _D = 500 mA; T _j = 150 °C	-	460	610	mΩ
		V_{GS} = 2.5 V; I _D = 400 mA; T _j = 25 °C	-	420	620	mΩ
		V_{GS} = 1.8 V; I _D = 100 mA; T _j = 25 °C	-	600	1100	mΩ
9 _{fs}	forward transconductance	V_{DS} = 10 V; I _D = 200 mA; T _j = 25 °C	-	1.6	-	S
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I_{D} = 500 mA; V_{GS} = 4.5 V;	-	0.45	0.68	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.15	-	nC
Q _{GD}	gate-drain charge		-	0.15	-	nC
C _{iss}	input capacitance	V_{DS} = 10 V; f = 1 MHz; V_{GS} = 0 V;	-	55	83	pF
C _{oss}	output capacitance	T _j = 25 °C	-	15	-	pF
C _{rss}	reverse transfer capacitance		-	7	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; R_L = 250 $\Omega;$ V_{GS} = 4.5 V;	-	6	12	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time		-	86	172	ns
t _f	fall time		-	31	-	ns
Source-d	rain diode					
V _{SD}	source-drain voltage	I _S = 300 mA; V _{GS} = 0 V; T _i = 25 °C	0.48	0.77	1.2	V

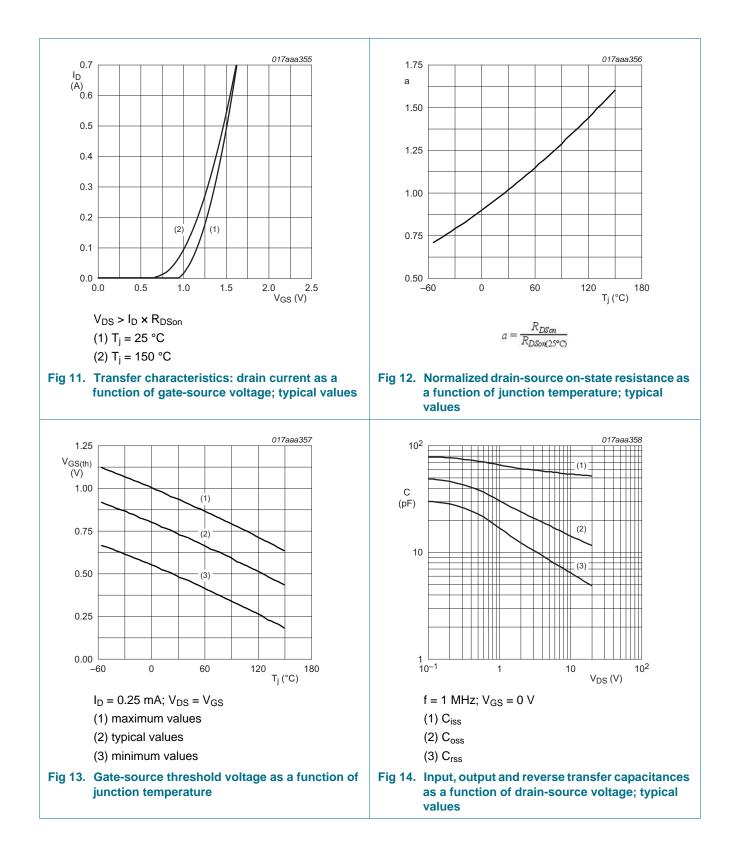
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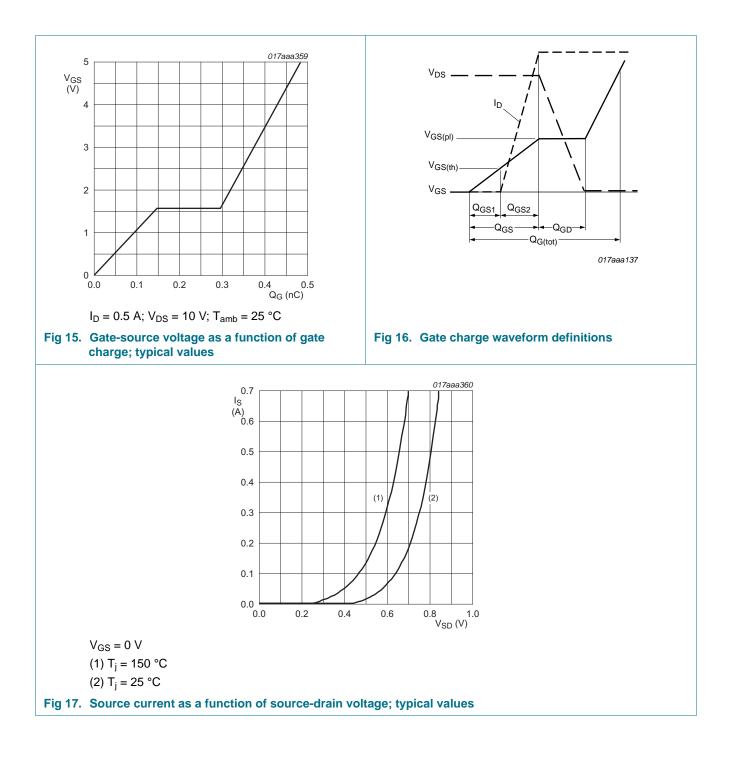
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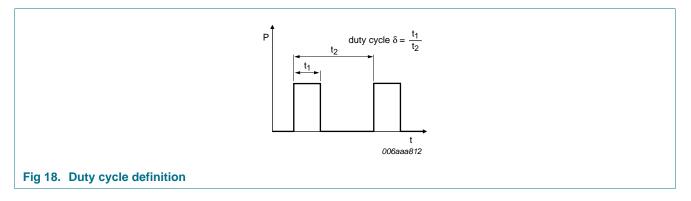
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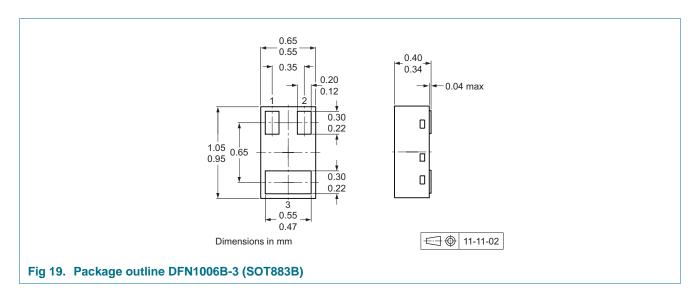


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8. Test information

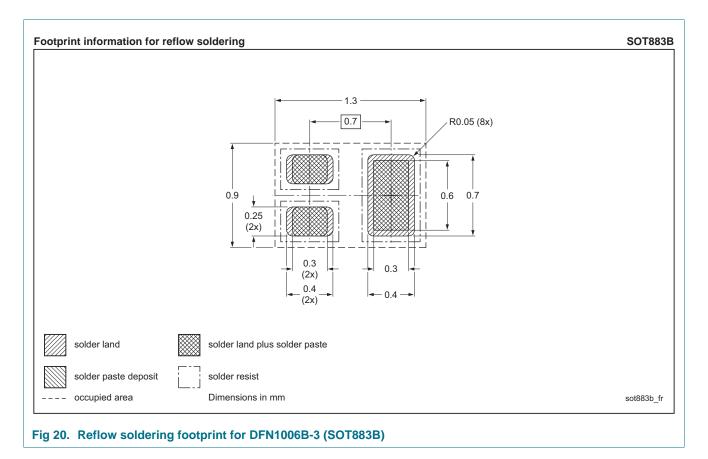


9. Package outline



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10. Soldering



11. Revision history

Table 8.Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMZB290UNE v.3	20120323	Product data sheet	-	PMZB290UNE v.2
Modifications:	 1.2 "Features 	and benefits" corrected.		
PMZB290UNE v.2	20120207	Product data sheet	-	PMZB290UNE v.1
PMZB290UNE v.1	20120201	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

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